Unit: mm

TOSHIBA Transistor Silicon PNP Epitaxial Type (PCT Process)

# RN2410, RN2411

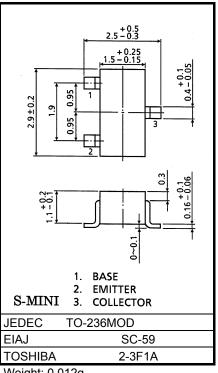
Switching, Inverter Circuit, Interface Circuit And Driver Circuit Applications

- With built-in bias resistors
- Simplified circuit design
- Reduce a quantity of parts and manufacturing process
- Complementary to RN1410, RN1411

### **Equivalent Circuit**

## Absolute Maximum Ratings (Ta = 25°C)

Characterisstic	Symbol	Rating	Unit	
Collector-base voltage	$V_{CBO}$	-50	V	
Collector-emitter voltage	V <sub>CEO</sub>	-50	٧	
Emitter-base voltage	V <sub>EBO</sub>	-5	٧	
Collector current	IC	-100	mA	
Collector power dissipation	PC	200	mW	
Junction temperature	Tj	150	°C	
Storage temperature range	T <sub>stg</sub>	-55~150	°C	



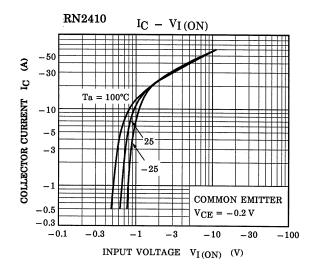
Weight: 0.012g

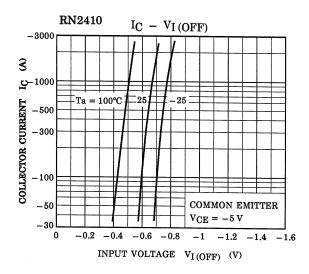
Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum

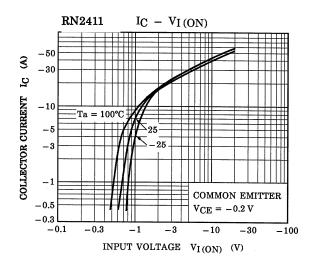
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions") Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

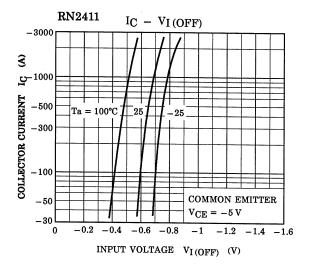
### **Electrical Characteristics (Ta = 25°C)**

Characteristic		Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current		I <sub>CBO</sub>	_	V <sub>CB</sub> = -50 V, I <sub>E</sub> = 0	_	_	-100	nA
Emitter cut-off current		I <sub>EBO</sub>	_	$V_{EB} = -5 \text{ V}, I_C = 0$	_	_	-100	nA
DC current gain		h <sub>FE</sub>	_	$V_{CE} = -5 \text{ V}, I_{C} = -1 \text{ mA}$	120	_	400	_
Collector-emitter saturation voltage		V <sub>CE</sub> (sat)	_	$I_C = -5 \text{ mA}, I_B = -0.25 \text{ mA}$	_	-0.1	-0.3	V
Translation frequency		f <sub>T</sub>	_	$V_{CE} = -10 \text{ V}, I_{C} = -5 \text{ mA}$	_	200	_	MHz
Collector output capacitance		$C_{\sf ob}$	_	$V_{CB} = -10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$	_	3	6	pF
Input resistor	RN2410	R1 —			3.29	4.7	6.11	kΩ
	RN2411		_		7	10	13	

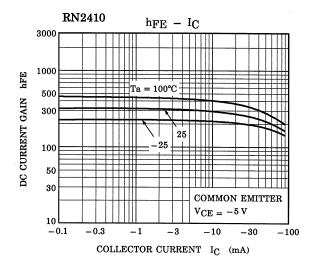


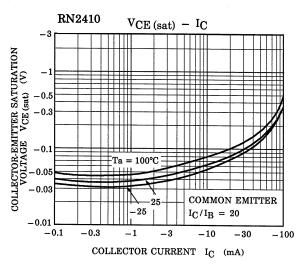


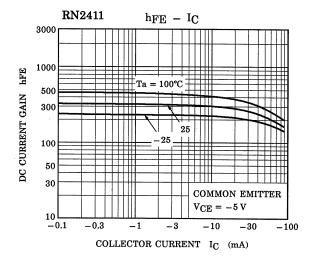


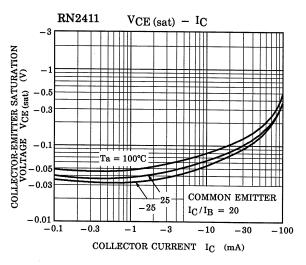


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Type Name	Marking	
RN2410	Type Name Y K	
RN2411	Type Name Y M	

2007-11-01

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20070701-EN GENERAL

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